



preliminary

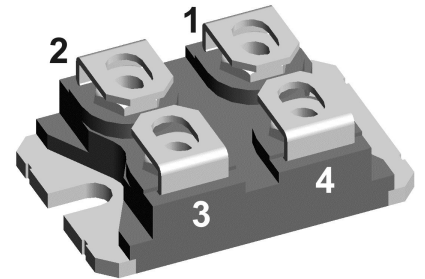
# HiPerFRED

$V_{RRM}$	=	200 V
$I_{FAV}$	= 2x	120 A
$t_{rr}$	=	55 ns

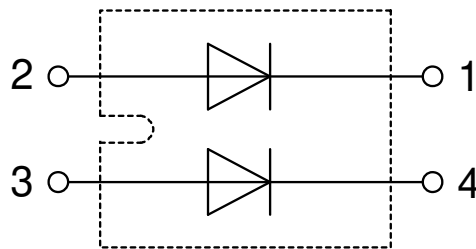
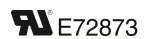
High Performance Fast Recovery Diode  
 Low Loss and Soft Recovery  
 Parallel legs

Part number

**DPF240X200NA**



Backside: isolated



### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{rm}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{rm}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

### Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

### Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper internally DCB isolated
- Advanced power cycling

### Disclaimer Notice

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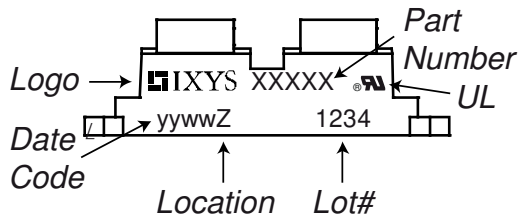


Fast Diode				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
$V_{RSM}$	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			200	V	
$V_{RRM}$	max. repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			200	V	
$I_R$	reverse current, drain current	$V_R = 200 V$	$T_{VJ} = 25^{\circ}C$		10	$\mu A$	
		$V_R = 200 V$	$T_{VJ} = 150^{\circ}C$		0.5	mA	
$V_F$	forward voltage drop	$I_F = 120 A$	$T_{VJ} = 25^{\circ}C$		1.19	V	
		$I_F = 240 A$			1.51	V	
		$I_F = 120 A$	$T_{VJ} = 150^{\circ}C$		1.06	V	
		$I_F = 240 A$			1.48	V	
$I_{FAV}$	average forward current	$T_C = 80^{\circ}C$ rectangular $d = 0.5$	$T_{VJ} = 150^{\circ}C$		120	A	
$V_{FO}$	threshold voltage	} for power loss calculation only	$T_{VJ} = 150^{\circ}C$		0.65	V	
$r_F$	slope resistance				3.4	m $\Omega$	
$R_{thJC}$	thermal resistance junction to case				0.4	K/W	
$R_{thCH}$	thermal resistance case to heatsink			0.10		K/W	
$P_{tot}$	total power dissipation		$T_C = 25^{\circ}C$		310	W	
$I_{FSM}$	max. forward surge current	$t = 10 ms; (50 Hz), sine; V_R = 0 V$	$T_{VJ} = 45^{\circ}C$		1.20	kA	
$C_J$	junction capacitance	$V_R = 100 V$ $f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		328	pF	
$I_{RM}$	max. reverse recovery current	} $I_F = 120 A; V_R = 100 V$ $-di_F / dt = 200 A/\mu s$	$T_{VJ} = 25^{\circ}C$		6	A	
			$T_{VJ} = 125^{\circ}C$		16	A	
$t_{rr}$	reverse recovery time		$T_{VJ} = 25^{\circ}C$		55	ns	
			$T_{VJ} = 125^{\circ}C$		85	ns	



Package SOT-227B (minibloc)		Ratings				
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			150	A
$T_{VJ}$	virtual junction temperature		-40		150	°C
$T_{op}$	operation temperature		-40		125	°C
$T_{stg}$	storage temperature		-40		150	°C
<b>Weight</b>				30		g
$M_D$	mounting torque		1.1		1.5	Nm
$M_T$	terminal torque		1.1		1.5	Nm
$d_{Spp/App}$	creepage distance on surface   striking distance through air	terminal to terminal	10.5	3.2		mm
$d_{Spb/Apb}$		terminal to backside	8.6	6.8		mm
$V_{ISOL}$	isolation voltage	t = 1 second	3000			V
		t = 1 minute	2500			V

**Product Marking**



**Part description**

- D = Diode
- P = HiPerFRED
- F = ultra fast
- 240 = Current Rating [A]
- X = Parallel legs
- 200 = Reverse Voltage [V]
- NA = SOT-227B (minibloc)

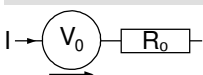
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DPF240X200NA	DPF240X200NA	Tube	10	512342

Similar Part	Package	Voltage class
DSEI2x121-02A	SOT-227B (minibloc)	200

**Equivalent Circuits for Simulation**

\* on die level

$T_{VJ} = 150^{\circ}C$



Symbol	Definition	Fast Diode	Unit
$V_{0\ max}$	threshold voltage	0.65	V
$R_{0\ max}$	slope resistance *	1.5	mΩ